



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





## InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz

### Typical Applications

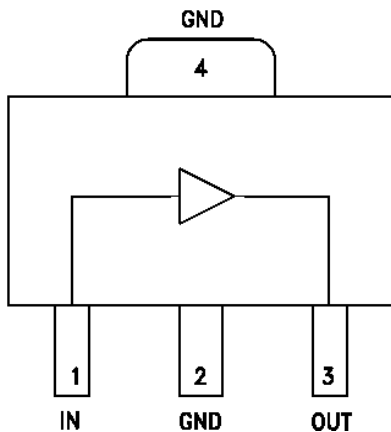
The HMC740ST89E is ideal for:

- Cellular/3G & WiMAX/4G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment
- IF & RF Applications

### Features

- P1dB Output Power: +18 dBm
- Gain: 15 dB
- Output IP3: +40 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +5V
- Industry Standard SOT89 Package
- Robust 1000V ESD, Class 1C
- Stable Current Over Temperature
- Active Bias Network

### Functional Diagram



### General Description

The HMC740ST89E is an InGaP Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifier covering 0.05 to 3 GHz. Packaged in an industry standard SOT89, the amplifier can be used as a cascadable 50 Ohm RF or IF gain stage as well as a PA or LO driver with up to +18 dBm output power. The HMC740ST89E offers 15 dB of gain with a +40 dBm output IP3 at 100 MHz, and can operate directly from a +5V supply. The HMC740ST89E exhibits excellent gain and output power stability over temperature, while requiring a minimal number of external bias components.

### Electrical Specifications, $V_{cc} = 5V$ , $T_A = +25^\circ C$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	0.05 - 1		0.05 - 3				GHz
Gain	12	15		11	15		dB
Gain Flatness		±0.1			±0.7		dB
Gain Variation over Temperature		0.003	0.006		0.003	0.006	dB/°C
Input Return Loss		18			15		dB
Output Return Loss		18			18		dB
Reverse Isolation		20			21		dB
Output Power for 1 dB Compression (P1dB)	15.5	18		14.5	17		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)		38			32		dBm
Noise Figure		3.5			3.5		dB
Supply Current (Icq)		88			88		mA

# HMC740\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

---

## COMPARABLE PARTS

View a parametric search of comparable parts.

## EVALUATION KITS

- HMC740ST89E Evaluation Board

## DOCUMENTATION

### Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers

### Data Sheet

- HMC740 Data Sheet

## TOOLS AND SIMULATIONS

- HMC740 S-Parameter

## REFERENCE MATERIALS

### Quality Documentation

- Package/Assembly Qualification Test Report: 3 Lead Plastic SOT89 Package (QTR: 10002 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-E (QTR: 2013-00271)

## DESIGN RESOURCES

- HMC740 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all HMC740 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK

Submit feedback for this data sheet.

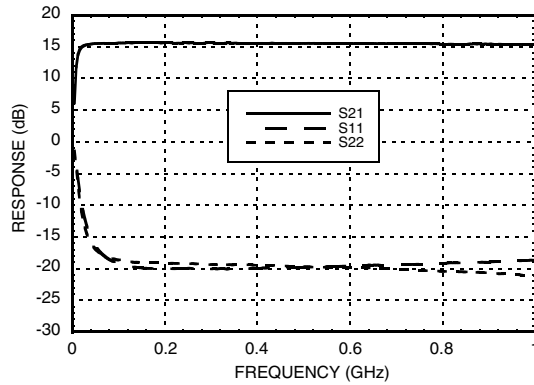
---



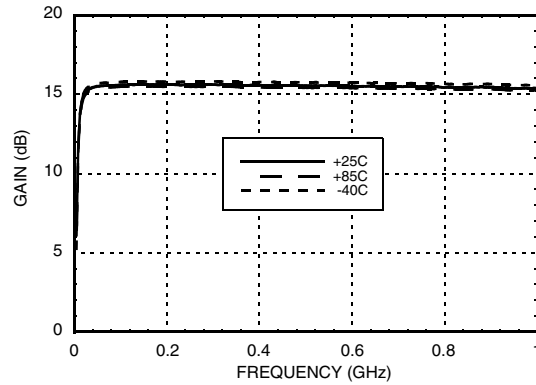
**InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz**

**IF Band Performance**

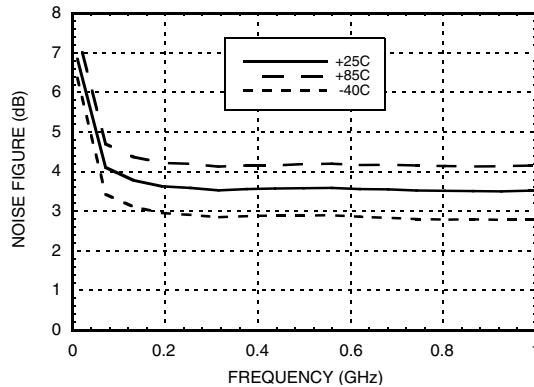
**Gain & Return Loss**



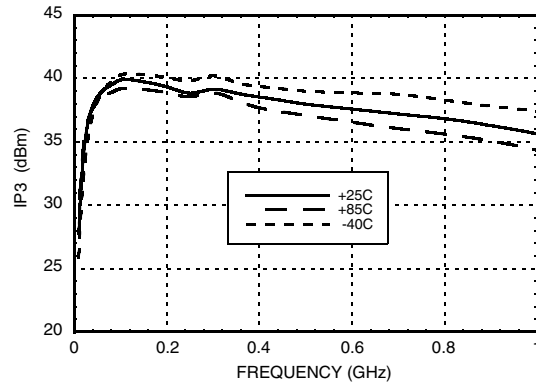
**Gain vs. Temperature**



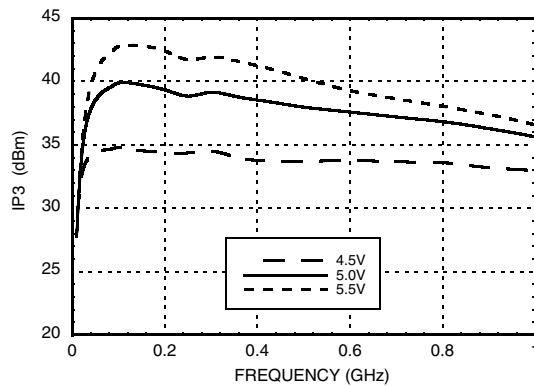
**Noise Figure vs. Temperature**



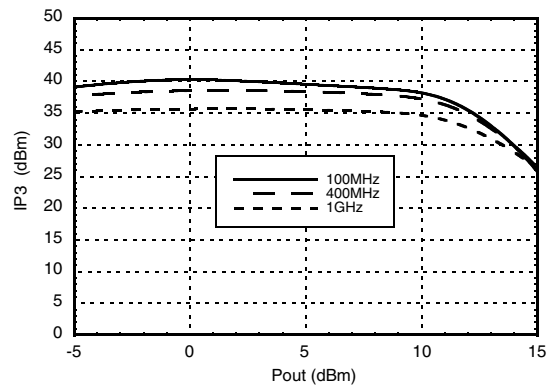
**Output IP3 vs. Temperature**



**Output IP3 vs. Vcc**



**Output IP3 vs. Output Power**



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

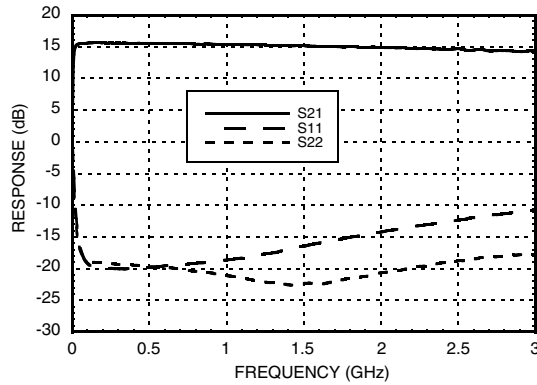
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



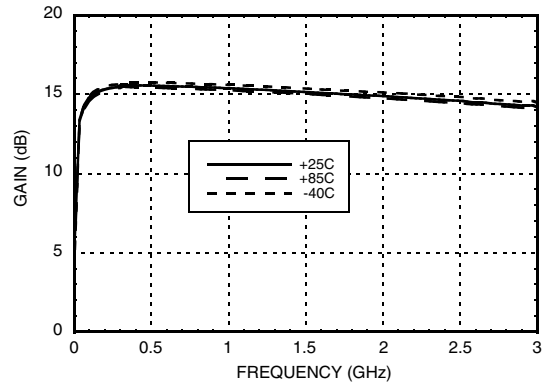
**InGaP HBT ACTIVE BIAS  
MMIC AMPLIFIER, 0.05 – 3 GHz**

**Broadband Performance**

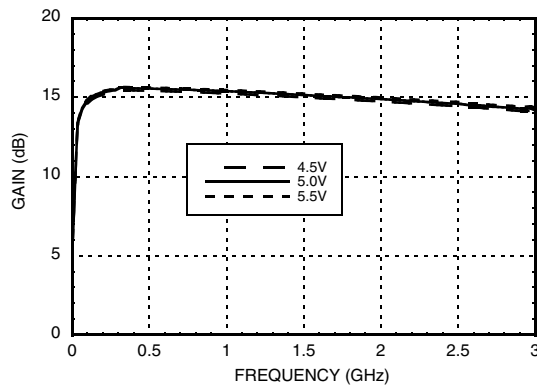
**Gain & Return Loss**



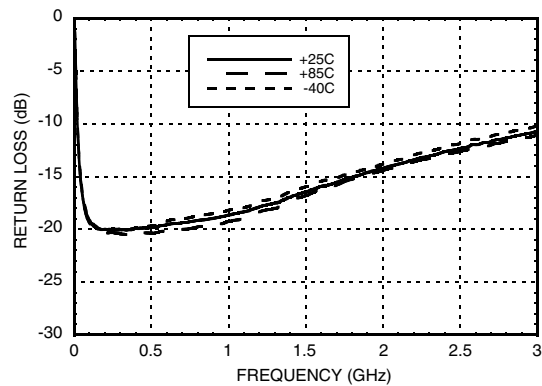
**Gain vs. Temperature**



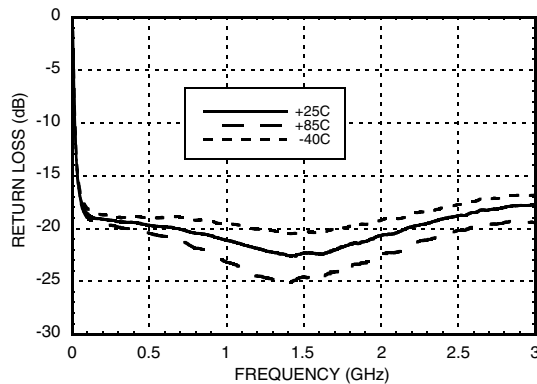
**Gain vs. Vcc**



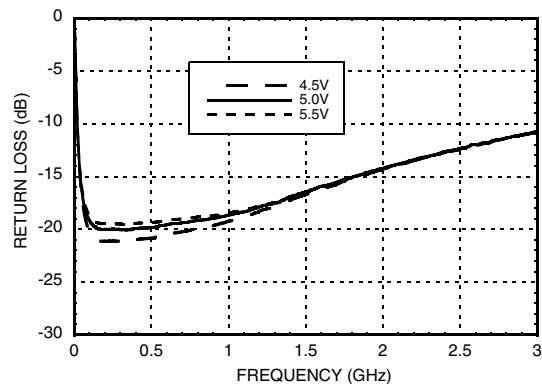
**Input Return Loss vs. Temperature**



**Output Return Loss vs. Temperature**



**Input Return Loss vs. Vcc**



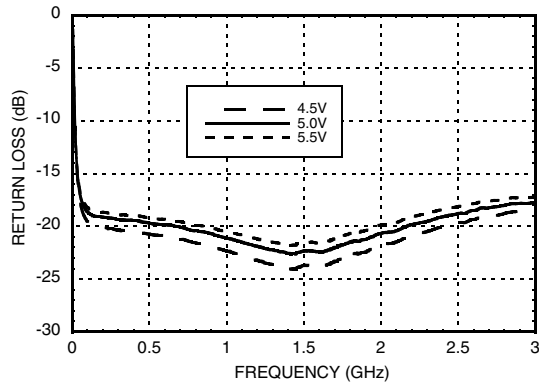
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D

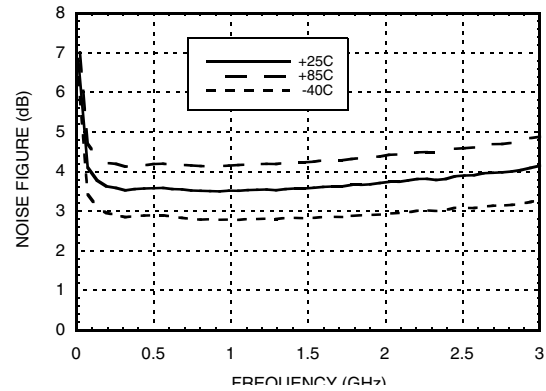


**InGaP HBT ACTIVE BIAS  
MMIC AMPLIFIER, 0.05 – 3 GHz**

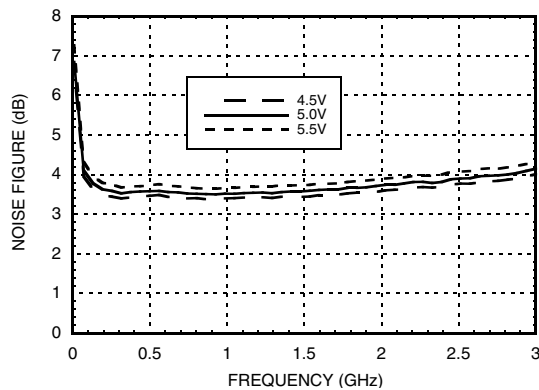
**Output Return Loss vs. Vcc**



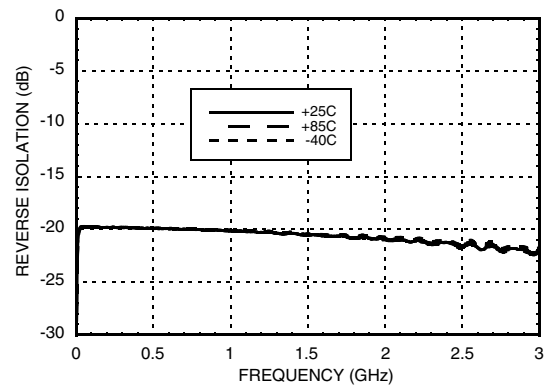
**Noise Figure vs. Temperature**



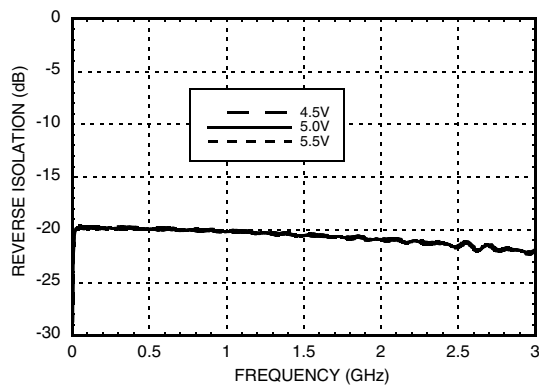
**Noise Figure vs. Vcc**



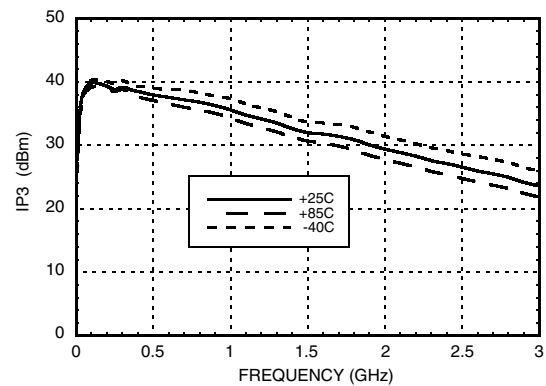
**Reverse Isolation vs. Temperature**



**Reverse Isolation vs. Vcc**



**Output IP3 vs. Temperature**



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D

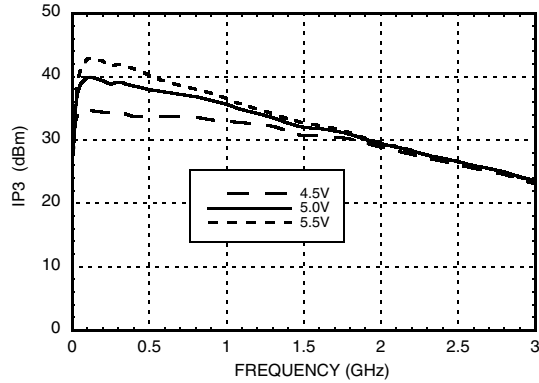


**InGaP HBT ACTIVE BIAS  
MMIC AMPLIFIER, 0.05 – 3 GHz**

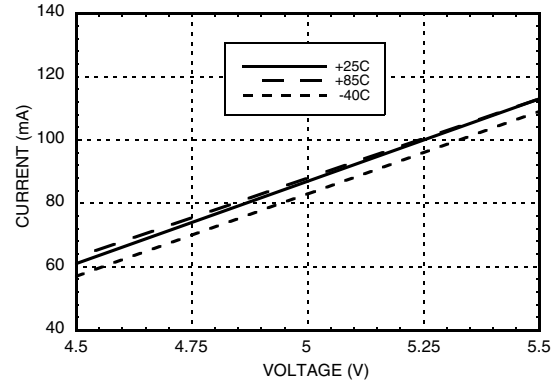
8

AMPLIFIERS - DRIVER & GAIN BLOCK - SMT

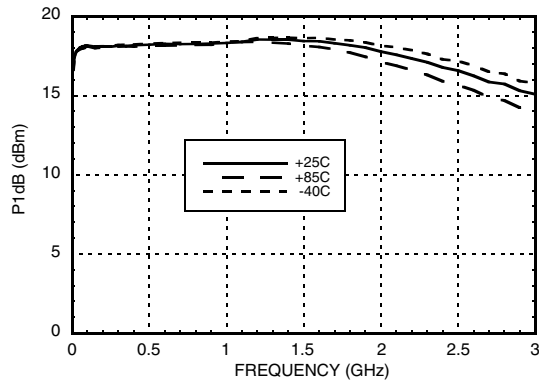
**Output IP3 vs. Vcc**



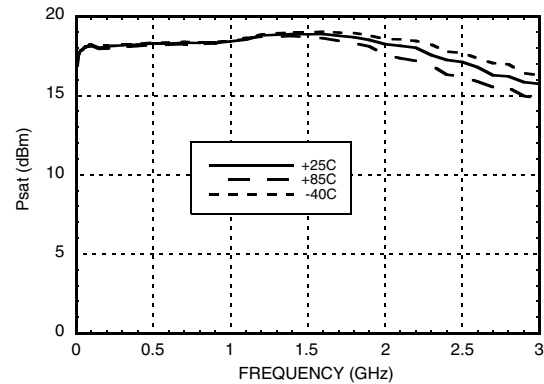
**Current vs. Temperature**



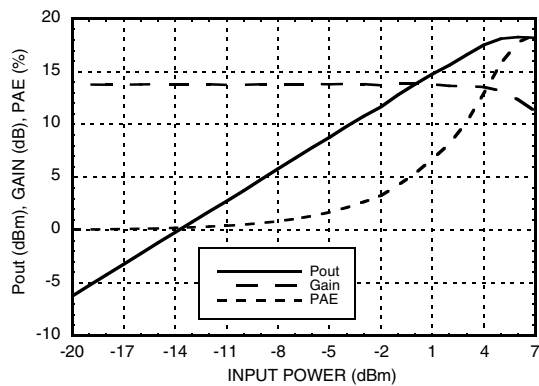
**P1dB vs. Temperature**



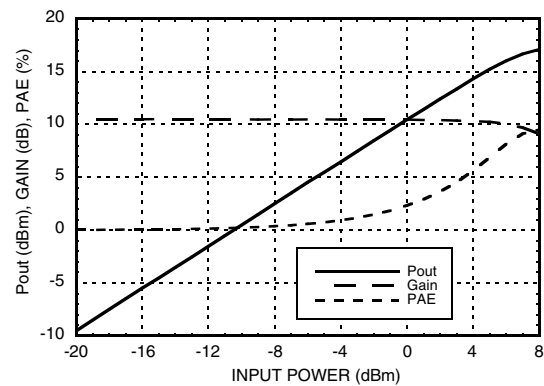
**Psat vs. Temperature**



**Power Compression @ 500 MHz**



**Power Compression @ 2 GHz**



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



## InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz

### Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+5.5 Vdc
RF Input Power (RFIN)	+15 dBm
Junction Temperature	150 °C
Continuous P <sub>diss</sub> (T = 85 °C) (derate 10.23 mW/°C above 85 °C)	0.66 W
Thermal Resistance (junction to lead)	97.78 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HMB)	Class 1C

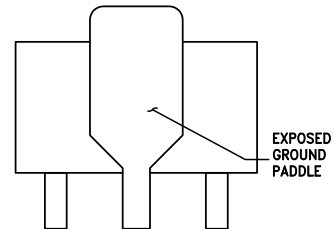
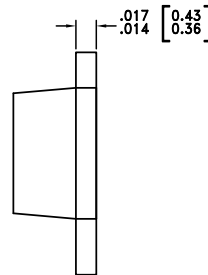
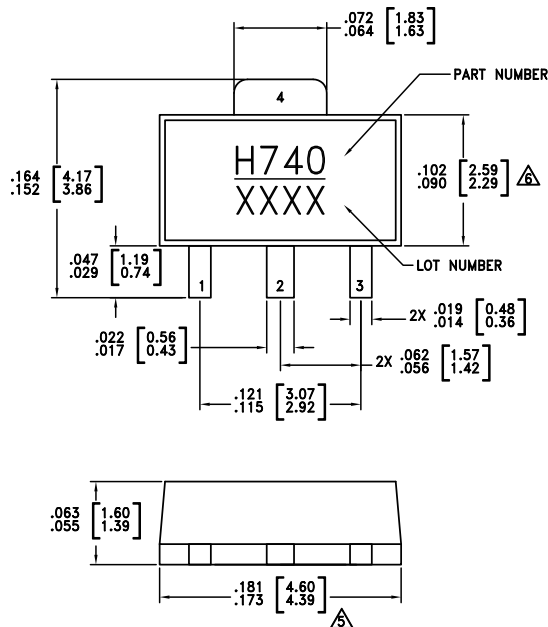


ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

8

AMPLIFIERS - DRIVER & GAIN BLOCK - SMT

### Outline Drawing



NOTES:

- PACKAGE BODY MATERIAL:  
MOLDING COMPOUND MP-180S OR EQUIVALENT.
- LEAD MATERIAL: Cu w/ Ag SPOT PLATING.
- LEAD PLATING: 100% MATTE TIN.
- DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

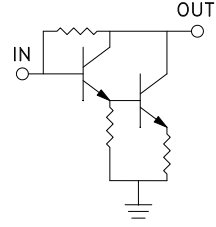

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[1]</sup>
HMC740ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	H740 XXXX

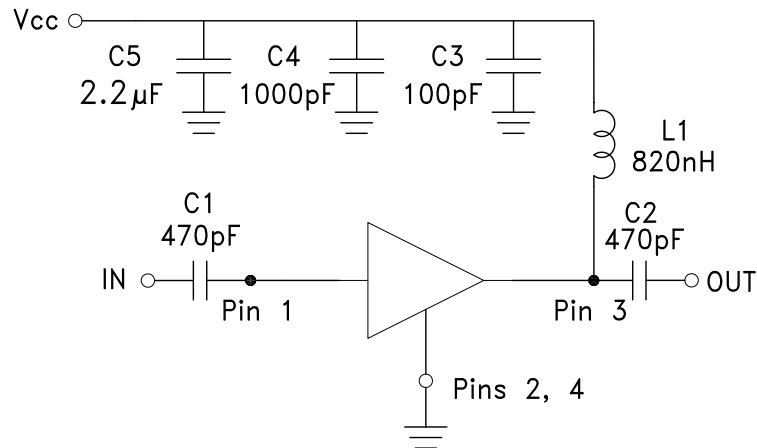
[1] 4-Digit lot number XXXX

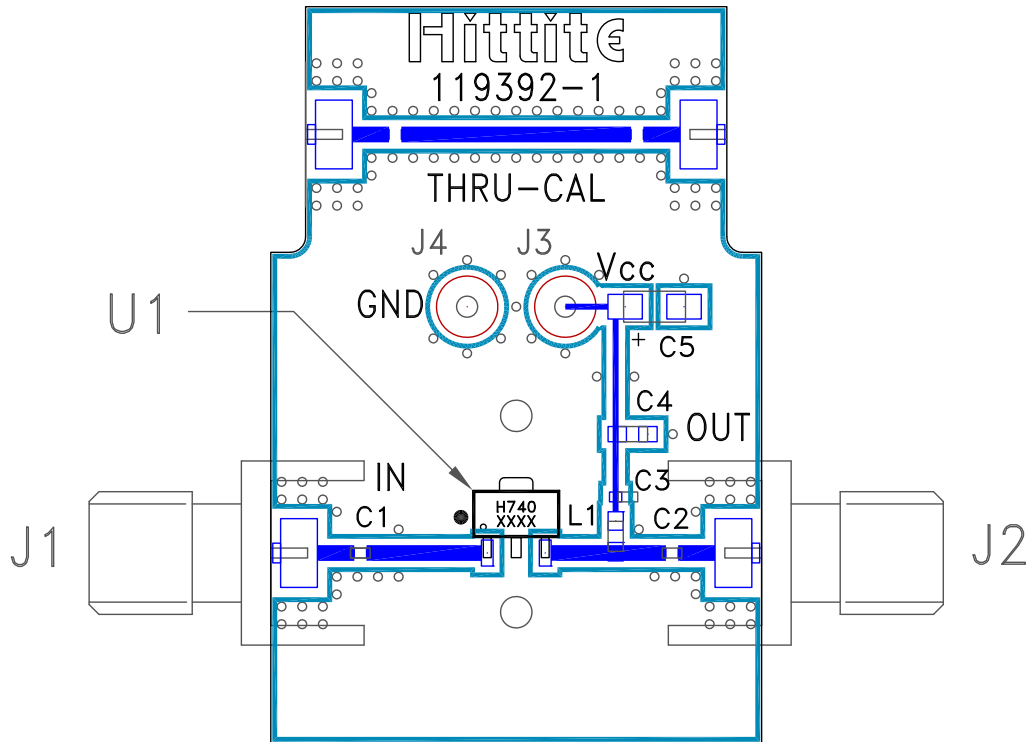
[2] Max peak reflow temperature of 260 °C




**InGaP HBT ACTIVE BIAS  
MMIC AMPLIFIER, 0.05 – 3 GHz**
**Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	IN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	OUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins and package bottom must be connected to RF/DC ground.	

**Application Circuit**



**InGaP HBT ACTIVE BIAS  
MMIC AMPLIFIER, 0.05 – 3 GHz**
**Evaluation PCB**

**List of Materials for Evaluation PCB 124390 [1]**

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Pin
C1, C2	470 pF Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 $\mu$ F Capacitor Tantalum
L1	820 nH Inductor, 0603 Pkg.
U1	HMC740ST89E
PCB [2]	119392 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: FR4

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.